



IRFBC30ASTRL Information



For Reference Only

Part Number IRFBC30ASTRL **Manufacturer** Vishay Siliconix

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

Translators TETS, WOOTETS SINGI

For the pricing/inventory/lead time, please contact

Description MOSFET N-CH 600V 3.6A D2PAK

Package TO-263-3, D2Pak (2 Leads + Tab), TO-263AB

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IRFBC30ASTRL Specifications

Manufacturer Part Number Manufacturer Vishay Siliconix Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - S Package TO-263-3, D2Pak (2 Leads + Tall Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C 3.6A (Tc)	
Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - 3 Package TO-263-3, D2Pak (2 Leads + Tall Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss)	
Transistors - FETs, MOSFETs - 3 Package TO-263-3, D2Pak (2 Leads + Tall Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Transistors - FETs, MOSFETs - 3 To-263-3, D2Pak (2 Leads + Tall Series) - FET Type N-Channel Technology MOSFET (Metal Oxide)	
Package TO-263-3, D2Pak (2 Leads + Tall Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 600V	Single
Series - N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 600V	~···-5
FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 600V	o), TO-263AB
Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 600V	
Drain to Source Voltage (Vdss) 600V	
Current - Continuous Drain (Id) @ 25°C 3,6A (Tc)	
Current Community C 20 C	
Drive Voltage (Max Rds On, Min Rds On) 10V	
$Vgs(th)$ (Max) @ Id 4.5V @ 250 μ A	
Gate Charge (Qg) (Max) @ Vgs 23nC @ 10V	
Input Capacitance (Ciss) (Max) @ Vds 510pF @ 25V	
Vgs (Max) ±30V	
FET Feature -	
Power Dissipation (Max) 74W (Tc)	
Rds On (Max) @ Id, Vgs 2.2 Ohm @ 2.2A, 10V	
Operating Temperature $-55^{\circ}\text{C} \sim 150^{\circ}\text{C} \text{ (TJ)}$	
Mounting Type Surface Mount	
Supplier Device Package D2PAK	
Package / Case TO-263-3, D2Pak (2 Leads + Tal	b) TO 263 A B
	0), 10-203AD

IRFBC30ASTRL Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRFBC30ASTRL Payment Methods





















IRFBC30ASTRL Shipping Methods













If you have any question about IRFBC30ASTRL, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com